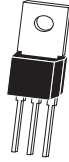




**CEN-U45**  
**NPN SILICON**  
**DARLINGTON TRANSISTOR**



**JEDEC TO-202 CASE**

# Central™

**Semiconductor Corp.**

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CEN-U45 type is an NPN Silicon Monolithic Darlington Transistor designed for applications requiring high gain and high power dissipation.

**MARKING CODE: FULL PART NUMBER**

**FEATURES:**

- High Collector current (2.0A)
- High DC current gain (25K MIN)
- Low Voltage (50V MAX)

**APPLICATIONS:**

- Designed for general purpose amplifiers and drivers

**MAXIMUM RATINGS:** (T<sub>A</sub>=25°C)

	SYMBOL		UNITS
Collector-Base Voltage	V <sub>CB0</sub>	50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	40	V
Collector-Emitter Voltage	V <sub>CES</sub>	40	V
Emitter-Base Voltage	V <sub>EBO</sub>	12	V
Collector Current	I <sub>C</sub>	2.0	A
Power Dissipation	P <sub>D</sub>	2.0	W
Power Dissipation (T <sub>C</sub> =25°C)	P <sub>D</sub>	10	W
Operating and Storage Junction Temperature	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C
Thermal Resistance	θ <sub>JA</sub>	62.5	°C/W
Thermal Resistance	θ <sub>JC</sub>	12.5	°C/W

**ELECTRICAL CHARACTERISTICS:** (T<sub>A</sub>=25°C unless otherwise noted)

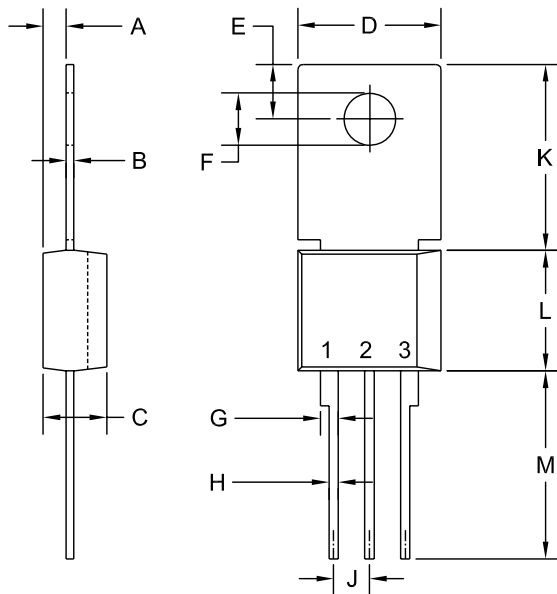
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I <sub>CB0</sub>	V <sub>CB</sub> =30V		100	nA
I <sub>EBO</sub>	V <sub>EB</sub> =10V		100	nA
BV <sub>CB0</sub>	I <sub>C</sub> =100µA	50		V
BV <sub>CES</sub>	I <sub>C</sub> =100µA	40		V
BV <sub>EBO</sub>	I <sub>E</sub> =10µA	12		V
V <sub>CE(SAT)</sub>	I <sub>C</sub> =1.0A, I <sub>B</sub> =2.0mA		1.5	V
V <sub>CE(SAT)</sub>	I <sub>C</sub> =200mA, I <sub>B</sub> =2.0mA		1.0	V
V <sub>BE(SAT)</sub>	I <sub>C</sub> =1.0A, I <sub>B</sub> =2.0mA		2.0	V
V <sub>BE(ON)</sub>	V <sub>CE</sub> =5.0V, I <sub>C</sub> =1.0A		2.0	V

R1 (28-August 2007)

**ELECTRICAL CHARACTERISTICS:** (continued)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
$h_{FE}$	$V_{CE}=5.0V, I_C=200mA$	25K	150K	
$h_{FE}$	$V_{CE}=5.0V, I_C=500mA$	15K		
$h_{FE}$	$V_{CE}=5.0V, I_C=1.0A$	4.0K		
$f_T$	$V_{CE}=5.0V, I_C=200mA, f=100MHz$	100		MHz
$C_{ob}$	$V_{CB}=10V, I_E=0, f=1.0MHz$		8.0	pF

**TO-202 CASE - MECHANICAL OUTLINE**



SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.055	0.071	1.40	1.80
B	0.016	0.024	0.40	0.60
C	0.173	0.181	4.40	4.60
D	0.374	0.413	9.50	10.50
E	0.146	0.154	3.70	3.90
F (DIA)	0.142	0.150	3.60	3.80
G	0.039	0.055	1.00	1.40
H	0.024	0.031	0.60	0.80
J	0.094	0.106	2.39	2.69
K	0.492	0.551	12.50	14.00
L	0.327	0.346	8.30	8.80
M	0.492	0.531	12.50	13.50

TO-202 (REV: R1)

R1

**LEAD CODE:**

- 1) EMITTER
- 2) BASE
- 3) COLLECTOR

**MARKING CODE: FULL PART NUMBER**

R1 (28-August 2007)